

MITSUBISHI LASER DIODES  
**ML7XX8 SERIES**  
 InGaAsP - MQW - FP LASER DIODES

**TYPE  
NAME**

**ML701B8R , ML725B8F , ML725C8F  
 ML720J8S , ML720K8S , ML725J8F**

**DESCRIPTION**

ML7XX8 series are InGaAsP laser diodes which provides a stable, single transverse mode oscillation with emission wavelength of 1310nm and standard continuous light output of 10mW.

ML7XX8 are hermetically sealed devices having the photo diode for optical output monitoring. This high-performance, high reliability, and long-life laser diode is suitable for such applications as the light sources for long distance optical communication systems.

**FEATURES**

- 1310nm typical emission wavelength
- Low threshold current, low operating current
- High-power, wide temp. range operation  
(Po=10mW, Tc=-40 to +85 deg.C)
- Have a lens-cap  
ML725C35F, ML720K35S = ball lens  
ML725J8F = Aspherical lens
- MQW\* active layer  
\* Multiple Quantum Well

**APPLICATION**

Optical communication system

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Conditions	Ratings[Note 1]	Unit
Po	Light output power	-	10[7]	mW
VRL	Reverse voltage (laser diode)	-	2	V
VRD	Reverse voltage (Photodiode)	-	20	V
IFD	Forward current (Photodiode)	-	2	mA
Tc	Case temperature	-	-40 ~ +85	deg.C
Tstg	Storage temperature	-	-40 ~ +100	deg.C

**ELECTRICAL/OPTICAL CHARACTERISTICS(Tc=25deg.C) [Note 1]**

Symbol	Parameter	Test conditions	Min.	Typ.	Max	Unit
I <sub>th</sub>	Threshold current	CW	-	5	15	mA
I <sub>op</sub>	Operating current	CW, Po=5mW	-	20	35	mA
V <sub>op</sub>	Operating voltage	CW, Po=5mW	-	1.1	1.5	V
η	Slope efficiency	CW, Po=5mW	0.3[0.2]	0.4[0.3]	-	mW/mA
λ <sub>p</sub>	Peak wavelength	CW, Po=5mW	1290	1310	1330	nm
Δλ	Spectral width (RMS)	CW, Po=5mW	-	1	2	nm
θ <sub>//</sub>	Beam divergence angle (parallel)	CW, Po=5mW	-	25[11]	-	deg.
θ <sub>⊥</sub>	Beam divergence angle (perpendicular)	CW, Po=5mW	-	30[11]	-	deg.
t <sub>r,tf</sub>	Rise and Fall time	If=I <sub>th</sub> , Po=5mW, 10 - 90%	-	0.3	0.7	ns
I <sub>m</sub>	Monitoring output current	CW, Po=5mW, V <sub>RD</sub> =1V	0.1	0.5	-	mA
I <sub>D</sub>	Dark current (Photodiode)	V <sub>RD</sub> =10V	-	0.01	0.1	μA
C <sub>t</sub>	Capacitance (Photodiode)	V <sub>RD</sub> =10V, f=1MHz	-	10	20	pF
P <sub>f</sub> (Note 2)	Fiber coupled power	CW, Po=5mW, S 10/125	[0.4/1.5]	[0.8/2.0]	[---]	mW
D <sub>f</sub> (Note 2)	Fiber coupled distance	CW, Po=5mW, S 10/125 (Note 3)	[5.0/6.0]	[5.8/7.5]	[6.2/9.0]	mm

Note 1 : [ ] applied to the lens cap type


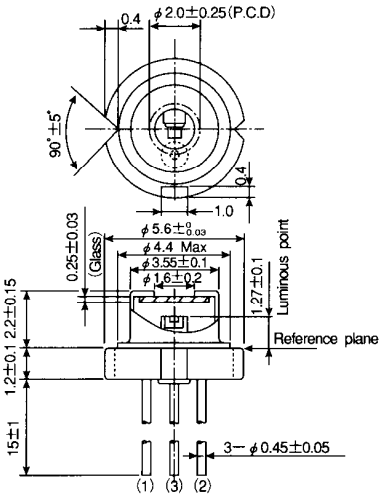
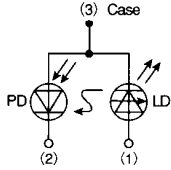
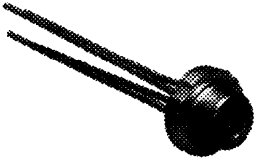
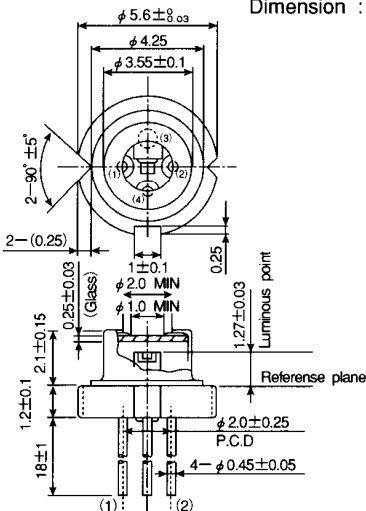
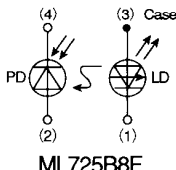
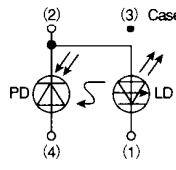
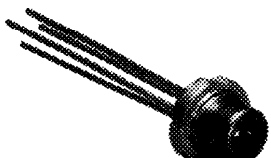
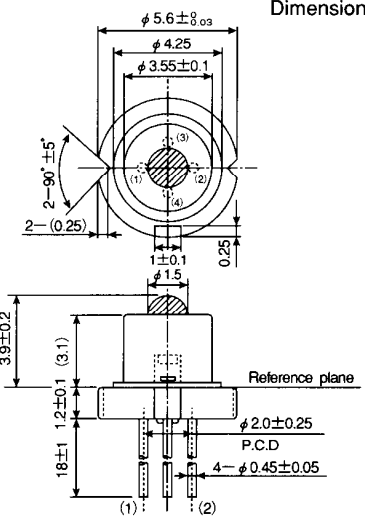
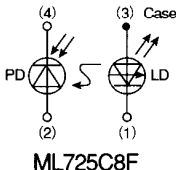
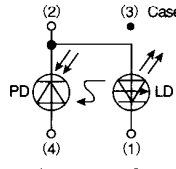
Note 2 : P<sub>f</sub>, D<sub>f</sub> are applied to the [ball lens type/aspherical lens type]

Note 3 : D<sub>f</sub> is a distance from the reference plane to the fiber.

MITSUBISHI LASER DIODES  
ML7XX8 SERIES

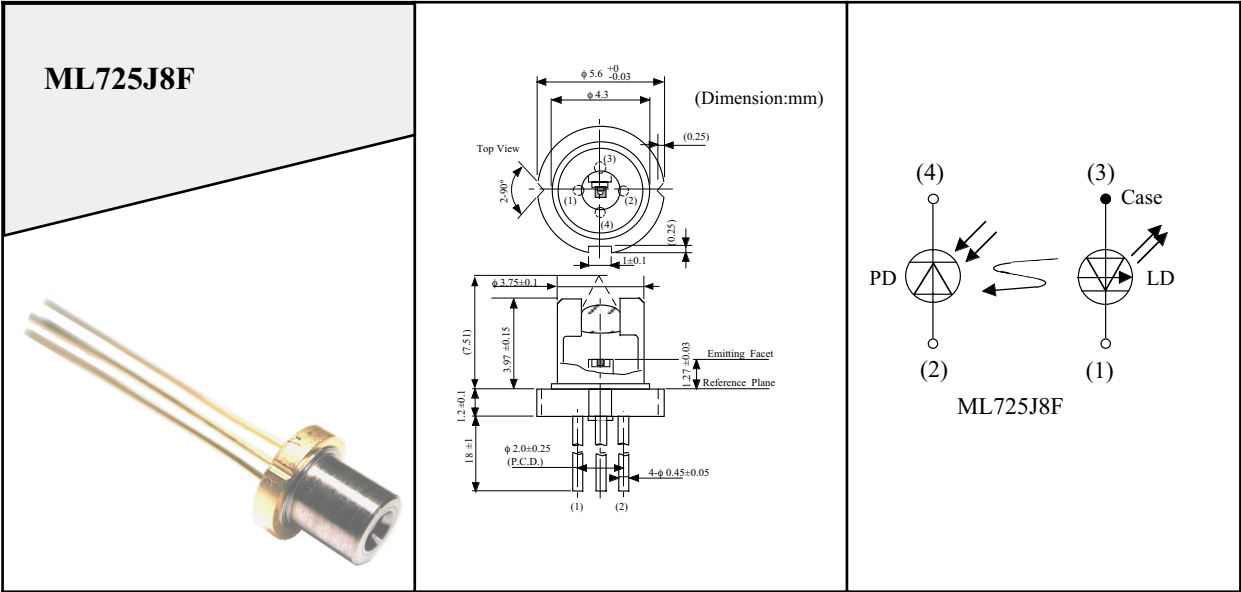
InGaAsP — MQW — FP LASER DIODES

OUTLINE DRAWINGS

<p>ML701B8R</p> 	<p>Dimension : mm</p> 	
<p>ML725B8F ML720J8S</p> 	<p>Dimension : mm</p> 	 <p>ML725B8F</p>  <p>ML720J8S</p>
<p>ML725C8F ML720K8S</p> 	<p>Dimension : mm</p> 	 <p>ML725C8F</p>  <p>ML720K8S</p>

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**InGaAsP-MQW-FP-LASER DIODES**

**OUTLINE DRAWINGS**



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ML7XX8 SERIES

InGaAsP —MQW—FP LASER DIODES

TYPICAL CHARACTERISTICS

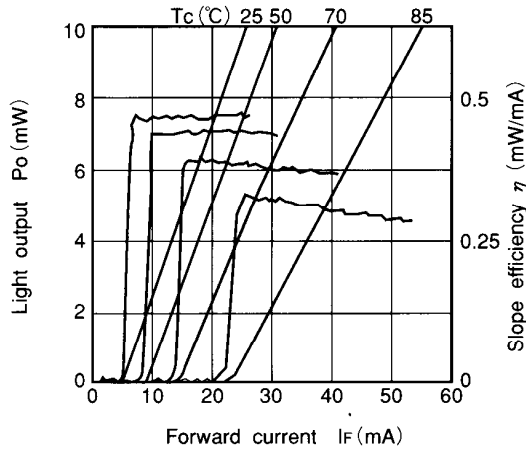


Fig.1 Light output vs. forward current

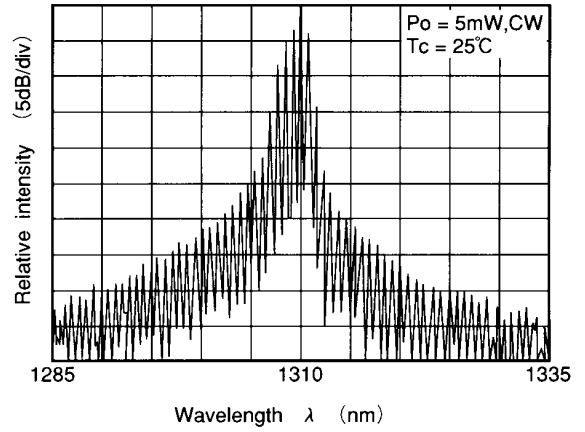


Fig.52 Spectrum

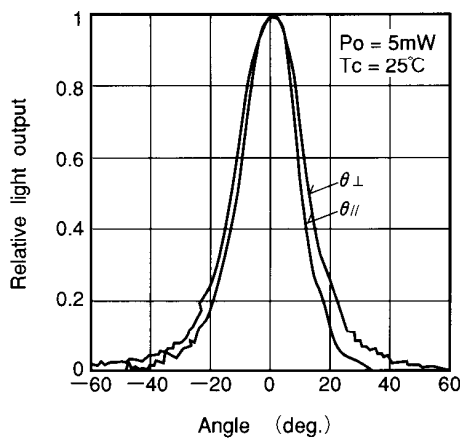


Fig.3 Far field pattern

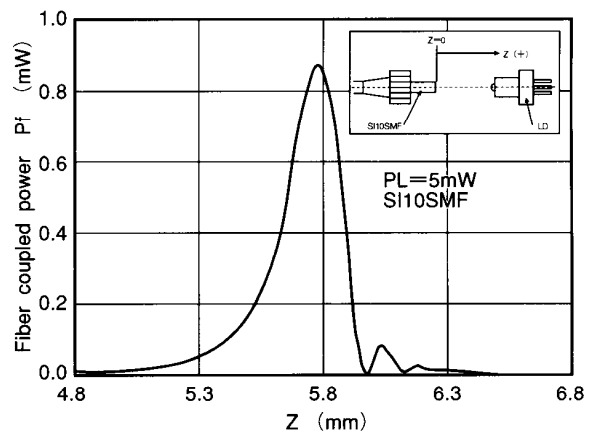
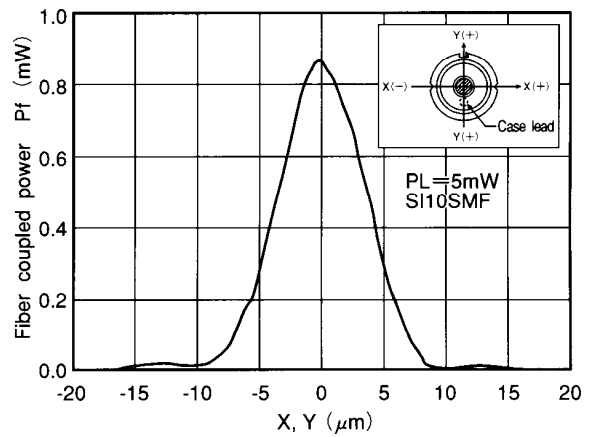


Fig.4 Fiber coupling characteristics  
(ML725C8F, ML720K8S)